

250132US-2TTCRD DIV

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

IN RE APPLICATION OF: :  
SHIHO OKUNO, ET AL. : GROUP UNIT:  
SERIAL NO: NEW DIV. APPLN. :  
FILED: HEREWITH : EXAMINER:  
FOR: MAGNETORESISTANCE EFFECT :  
ELEMENT, ITS MANUFACTURING  
METHOD, MAGNETIC REPRODUCING  
ELEMENT AND MAGNETIC MEMORY

PRELIMINARY AMENDMENT

COMMISSIONER FOR PATENTS  
ALEXANDRIA, VIRGINIA 22313

SIR:

Prior to initial examination on the merits, please amend the above-identified application as follows:

**Amendments to the Specification** begin on page 2 of this paper

**Listing of the Claims** begins on page 3 of this paper.

**Remarks** begin on page 5 of this paper.